Vishay Semiconductors

High Performance Schottky Rectifier, 1 A

FEATURES

- Low forward voltage drop
- · Guard ring for enhanced ruggedness and long term reliability
- · Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- AEC-Q101 gualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-10BQ100HM3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	1	А		
V _{RRM}		100	V		
I _{FSM}	t _p = 5 μs sine	780	А		
V _F	1.0 A _{pk} , T _J = 125 °C	0.59	V		
TJ	Range	-55 to +175	°C		

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-10BQ100HM3	UNITS		
Maximum DC reverse voltage	V _R	100	M		
Maximum working peak reverse voltage	V _{RWM}	100	v		

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T_L = 143 °C, rectangular waveform		1.0	А
Maximum peak one cycle non-repetitive surge current	I _{FSM}	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	780	A
		10 ms sine or 6 ms rect. pulse		38	
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 0.5 A, L = 8 mH		1.0	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		0.5	А

Revision: 17-Dec-14 Document Number: 95725 1 For technical questions within your region: DiodesAmericas@vishav.com, DiodesAsia@vishav.com, DiodesEurope@vishav.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000



RoHS

COMPLIANT

HALOGEN

FREE





PRODUCT SUMMARY			
Package	SMB		
I _{F(AV)}	1 A		
V _R	100 V		
V _F at I _F	0.59 V		
I _{RM}	1 mA at 125 °C		
T _J max.	175 °C		
Diode variation	Single die		
E _{AS}	1.0 mJ		





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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop See fig. 1	V _{FM} ⁽¹⁾	1 A	T _J = 25 °C	0.75	V
		2 A		0.82	
		1 A	- T _J = 125 °C	0.59	
		2 A		0.65	
Maximum reverse leakage current See fig. 2	I _{RM}	T _J = 25 °C	V _R = Rated V _R	0.5	mA
		T _J = 125 °C		1	
Typical junction capacitance	CT	$V_{\rm R}$ = 5 $V_{\rm DC}$, (test signal range 100 kHz to 1 MHz), 25 °C		65	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		2.0	nH
Maximum voltage rate of charge	dV/dt	Rated V _R		10 000	V/µs

Note

⁽¹⁾ Pulse width = 300 μ s, duty cycle = 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		-55 to +175	°C
Maximum thermal resistance, junction to lead	R _{thJL} ⁽²⁾	DC operation	36	°C/W
Maximum thermal resistance, junction to ambient	R _{thJA}		80	°C/W
Approximate weight			0.10	g
		0.003	oz.	
Marking device		Case style SMB (similar DO-214AA)	1J	

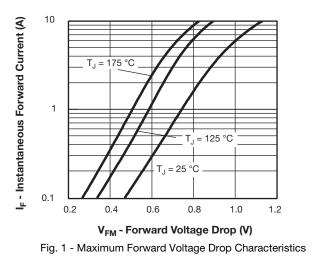
Notes

 $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink (1)

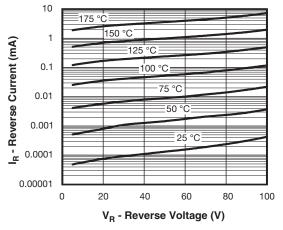
(2) Mounted 1" square PCB

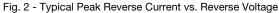
VS-10BQ100HM3

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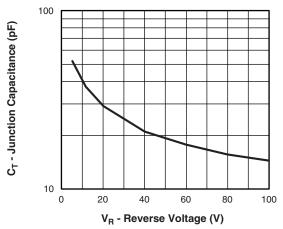
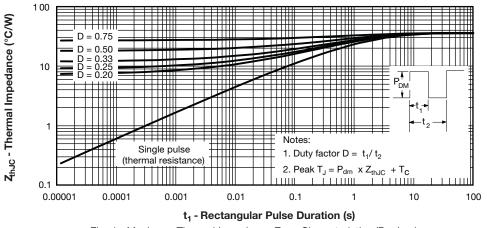
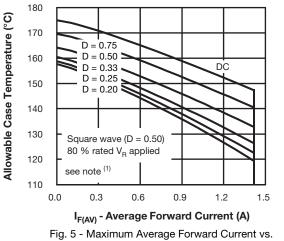


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



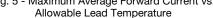
VS-10BQ100HM3

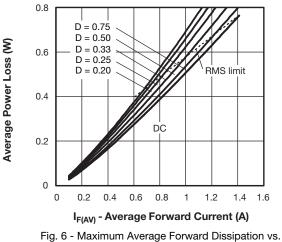
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ISHAY





Average Forward Current

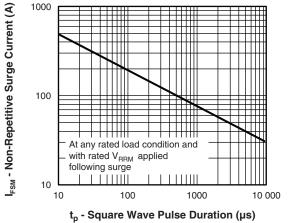


Fig. 7 - Maximum Peak Surge Forward Current vs. Pulse Duration

Note

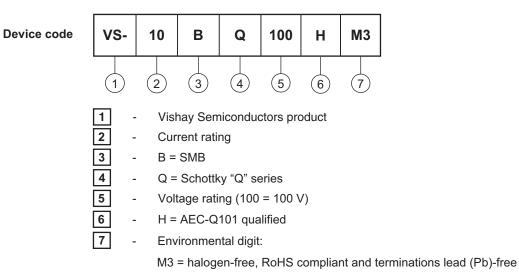
⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \, x \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \, x \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

VS-10BQ100HM3



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ORDERING INFORMATION TABLE



 ORDERING INFORMATION (Example)

 PREFERRED P/N
 PREFERRED PACKAGE CODE
 MINIMUM ORDER QUANTITY
 PACKAGING DESCRIPTION

 VS-10BQ100HM3/5BT
 5BT
 3200
 13" diameter plastic tape and reel

LINKS TO RELATED DOCUMENTS		
Dimensions	www.vishay.com/doc?95401	
Part marking information	www.vishay.com/doc?95403	
Packaging information	www.vishay.com/doc?95404	

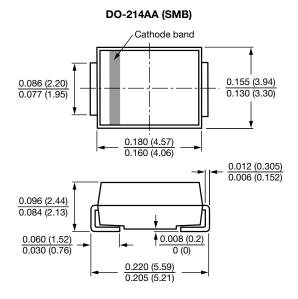


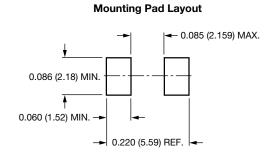
Outline Dimensions

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SMB

DIMENSIONS in inches (millimeters)







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